

# **Applications Note:SY58594A**

Single Stage Buck PFC Regulator For LED Lighting Preliminary Specification

### **General Description**

The SY58594A is a single stage Buck PFC controller targeting at LED lighting applications. It integrates a 600V MOSFET to decrease physical volume. It adopts the proprietary control architecture to achieve an accurate regulation of LED current, unity power factor, and quasi-resonant valley turn-on high efficiency operation.

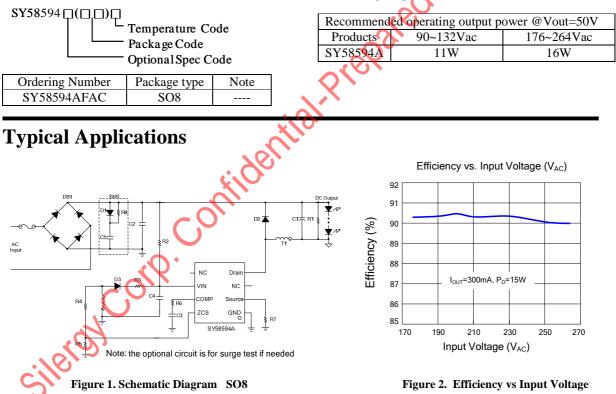
It integrates open/short LED protection and eliminates the need for opto-coupler, thus minimizing the component count and board size.

### **Ordering Information**

### Features

- Integrated 600V MOSFET
- Valley turn-on of the MOSFET to achieve low switching losses
- 0.3V current sense reference voltage leads to a lower sense resistance thus a lower conduction loss.
- Low start up current: 15µA typical
- Reliable short LED and Open LED protection
- Power factor >0.90 with single-stage conversion.
- Maximum frequency limit: 200kHz
- Compact package: SO8

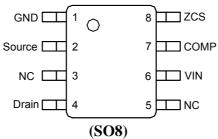
# ApplicationsLED lighting



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**Pinout** (top view)



Top Mark: AMJxyz (device code:AMJ, x=year code, y=week code, z= lot number code)

Pin Name	Pin number SO8	Pin Description
GND	1	Ground pin
Source	2	Source pin of the internal MOSFET. Connect the sense resistor to this Pin and the GND pin. (current sense resister $R_S$ : $R_s = \frac{V_{REF}}{2 \times I_{OUT}}$ )
NC	3	Leave it floating
Drain	4	Drain of the internal power MOSFET
NC	5	Leave it floating
VIN	6	Power supply pin. This pin also provides output over voltage protection along with ZCS pin.
COMP	7	Loop compensation pm. Connect a RC network across this pin and ground to stabilize the control loop.
ZCS	8	Inductor current zero-crossing detection pin. This pin receives the auxiliary winding voltage by a resister divider and detects the inducto current zero crossing point. This pin also provides over voltage protection and line regulation modification function simultaneously. If the voltage or this pin is above $V_{ZCS,OVP}$ , the IC would enter over voltage protection mode. Good line regulation can be achieved by adjusting the upper resistor of the divider.
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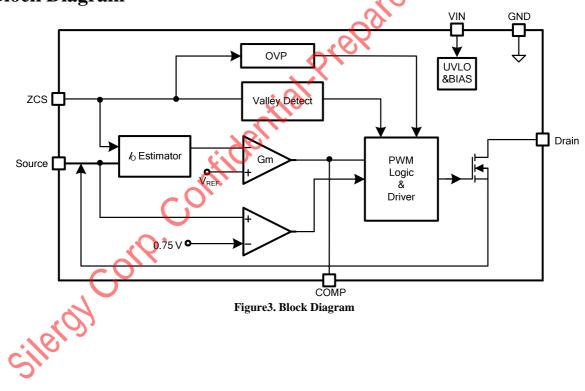


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### Absolute Maximum Ratings (Note 1)

VIN	
Supply current I <sub>VIN</sub>	30mA
ZCS	
COMP,Source	
Drain	600V
Power Dissipation, @ TA = 25°C SO8	1.1W
Package Thermal Resistance (Note 2)	
SO8, θ JA	88°C/W
SO8, θ JC	45°C/W
Junction Temperature Range	40°C to 150°C
Lead Temperature (Soldering, 10 sec.)	
Storage Temperature Range	

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### **Electrical Characteristics**

$(V_{IN} = 12V \text{ (Note 3)}, T_A = 25^{\circ}$		wise specified)						
Parameter Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit		
Power Supply Section								
Input voltage range	V <sub>VIN</sub>		8		15.4	V		
VIN turn-on threshold	V <sub>VIN,ON</sub>				17.6	V		
VIN turn-off threshold	V <sub>VIN,OFF</sub>		6.0		7.9	V		
VIN OVP voltage	V <sub>VIN,OVP</sub>			$V_{VIN_ON}+0.85$		V		
Start up Current	I <sub>ST</sub>	V <sub>VIN</sub> <v<sub>VIN,OFF</v<sub>		15		μA		
Operating Current	I <sub>VIN</sub>	C <sub>L</sub> =100pF,f=15kHz		1		mA		
Shunt current in OVP mode	I <sub>VIN,OVP</sub>	V <sub>VIN</sub> >V <sub>VIN,OVP</sub>	1.6	2	2.5	mA		
Error Amplifier Section				4				
Internal reference voltage	V <sub>REF</sub>		0.594	0.3	0.306	V		
ZCS pin Section				· · · ·				
ZCS pin OVP voltage	V		1.37	1.44	1.51	v		
threshold	V <sub>ZCS,OVP</sub>		1.57	1.44	1.51	v		
Integrated MOSFET Section	-			<u> </u>				
Breakdown Voltage	V <sub>BV</sub>	$V_{GS}=0V, I_{DS}=250\mu A$	600			V		
Current Sense Section(Source	e pin of integra	ted MOSFET)	.0.					
Current limit reference	V <sub>Source,MAX</sub>		N~	0.75		V		
voltage	<ul> <li>Source,MAX</li> </ul>	<u> </u>	5	0.75		v		
PWM Section	-				-			
Max ON Time	T <sub>ON,MAX</sub>	V <sub>COMP</sub> =1.5V		16		μs		
Min ON Time	T <sub>ON,MIN</sub>			400		ns		
Max OFF Time	T <sub>OFF,MAX</sub>			69		μs		
Min OFF Time	T <sub>OFF,MIN</sub>	X		2		μs		
Maximum switching	f <sub>MAX</sub>			200		kHz		
frequency	IMAX	761		200		KIIZ		
Thermal Section	¢	0						
Thermal Shutdown	T <sub>SD</sub>			150		°C		
Temperature	<sup>+</sup> SD			150		C		

**Note 1**: Stresses beyond the "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only. Functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

**Note 2**:  $\theta_{JA}$  is measured in the natural convection at  $T_A = 25^{\circ}$ C on a low effective single layer thermal conductivity test board of JEDEC 51-3 thermal measurement standard. Test condition: Device mounted on 2" x 2" FR-4 substrate PCB, 2oz copper, with minimum recommended pad on top layer and thermal vias to bottom layer ground plane.

Note 3: Increase VIN pin voltage gradually higher than  $V_{VIN,ON}$  voltage then turn down to 12V.



### <u>SY58594A</u>

The SY58594A is a single stage Buck PFC regulator targeting at LED lighting applications.

It integrates a MOSFET with 600V breakdown voltage to decrease physical volume.

High power factor is achieved by constant on-time operation mode, with which the control scheme and the circuit structure are both simple.

In order to reduce the switching losses and improve EMI performance, Quasi-Resonant switching mode is applied, which means to turn on the power MOSFET at valley of drain voltage; the start up current of SY58594A is rather small (15 $\mu$ A typically) to reduce the standby power loss further; the maximum switching frequency is clamped to 200kHz to reduce switching losses and improve EMI performance when the converter is operated at light load condition.

SY58594A is available with SO8 package.

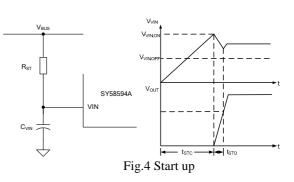
### **Applications Information**

#### <u>Start up</u>

After AC supply or DC BUS is powered on, the capacitor  $C_{VIN}$  across VIN and GND pin is charged up by BUS voltage through a start up resistor  $R_{ST}$ . Once  $V_{VIN}$  rises up to  $V_{VIN-ON}$ , the internal blocks start to work.  $V_{VIN}$  will be pulled down by internal consumption of IC until the auxiliary winding of Buck transformer could supply enough energy to maintain  $V_{VIN}$  above  $V_{VIN-OFF}$ .

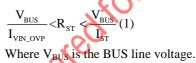
The whole start up procedure is divided into two sections shown in Fig.4.  $t_{\rm STC}$  is the  $C_{\rm VIN}$  charged up section, and  $t_{\rm STO}$  is the output voltage built-up section. The start up time  $t_{\rm ST}$  composes of  $t_{\rm STC}$  and  $t_{\rm STO}$ , and usually  $t_{\rm STO}$  is much smaller than  $t_{\rm STC}$ .





The start up resistor  $R_{ST}$  and  $C_{VIN}$  are designed by rules below:

(a) Preset start-up resistor  $R_{ST}$ , make sure that the current through  $R_{ST}$  is larger than  $I_{ST}$  and smaller than  $I_{VIN-OVP}$ 



(b) Select  $C_{VIN}$  to obtain an ideal start up time  $t_{ST}$ , and ensure the output voltage is built up at one time.

$$C_{VIN} = \frac{(\frac{V_{BUS}}{R_{ST}} - I_{ST}) \times t_{ST}}{V_{VIN_{ON}}} (2)$$

(d) If the  $C_{VIN}$  is not big enough to build up the output voltage at one time. Increase  $C_{VIN}$  and decrease  $R_{ST}$ , go back to step (a) and redo such design flow until the ideal start up procedure is obtained.

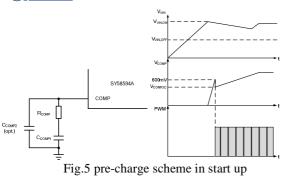
#### Internal pre-charge design for quick start up

After  $V_{VIN}$  exceeds  $V_{VIN,ON}$ ,  $V_{COMP}$  is pre-charged by an internal current source. The PWM block won't start to output PWM signals until  $V_{COMP}$  is over the initial voltage  $V_{COMP,IC}$ , which can be programmed by  $R_{COMP}$ . Such design is meant to reduce the start up time shown in Fig.5.

The voltage pre-charged  $V_{COMP\_IC}$  in start-up procedure can be programmed by  $R_{COMP}$ 

 $V_{\text{COMP IC}} = 600 \text{mV} - 300 \mu \text{A} \times \text{R}_{\text{COMP}} (3)$ 





Where  $V_{\text{COMP-IC}}$  is the pre-charged voltage of COMP pin.

Generally, a big capacitance of  $C_{COMP}$  is necessary to achieve high power factor and stabilize the system loop (1 $\mu$ F~2 $\mu$ F recommended); The voltage pre-charged in start-up procedure can be programmed by R<sub>COMP</sub>; On the other hand, larger R<sub>COMP</sub> can provide larger phase margin for the control loop; A small ceramic capacitor is added to suppress high frequency interruption (10pF~100pF is recommended if necessary)

#### Shut down

After AC supply or DC BUS is powered off, the energy stored in the BUS capacitor will be discharged. When the auxiliary winding of Buck transformer can not supply enough energy to VIN pin,  $V_{VIN}$  will drop down. Once  $V_{VIN}$  is below  $V_{VIN-OFF}$ , the IC will stop working and  $V_{COMP}$  will be discharged to zero.

#### **Constant-current control**

The switching waveforms are shown in Fig.6. The output current  $I_{OUT}$  can be represented by

$$I_{OUT} = \frac{I_{PK}}{2} \times \frac{t_{EFF}}{t_s}$$
(4)

Where  $I_{PK}$  is the peak current of the inductor;  $t_{EFF}$  is the effective time of inductor current rising and falling;  $t_s$  is the switching period.

 $I_{PK}$  and  $t_{EFF}$  can be detected by Source and ZCS pin, which is shown in Fig.7. These singals are processed and applied to the negative input of the gain modulator. In static state, the positive and negative inputs are equal.

$$V_{\text{REF}} = I_{\text{PK}} \times R_{\text{S}} \times \frac{t_{\text{EFF}}}{t_{\text{S}}} (5)$$

### <u>SY58594A</u>

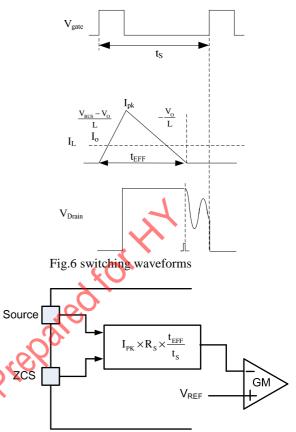


Fig.7 Output current detection diagram

Finally, the output current I<sub>OUT</sub> can represented by

$$I_{\rm OUT} = \frac{V_{\rm REF}}{R_{\rm S} \times 2} (6)$$

Where  $V_{REF}$  is the internal reference voltage;  $R_S$  is the current sense resistor.

 $V_{REF}$  is internal constant parameters,  $I_{OUT}$  can be programmed by  $R_s$ .

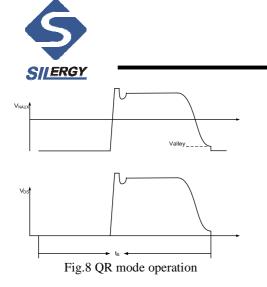
$$R_{s} = \frac{V_{REF}}{I_{OUT} \times 2} (7)$$

#### **Quasi-Resonant Operation**

QR mode operation provides low turn-on switching losses for Buck converter.

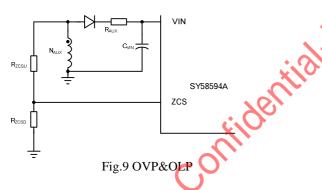
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### <u>SY58594A</u>



The voltage across drain and source of the integrated MOSFET is reflected by the auxiliary winding of the Buck transformer. ZCS pin detects the voltage across the auxiliary winding by a resistor divider. When the voltage across drain and source of the integrated MOSFET is at voltage valley, the MOSFET would be turned on.

#### Over Voltage Protection (OVP) & Open LED Protection (OLP)



The output voltage is reflected by the auxiliary winding voltage of the Buck transformer, and both ZCS pin and VIN pin provide over voltage protection function. When the load is null or large transient happens, the output voltage will exceed the rated value. When  $V_{VIN}$  exceeds  $V_{VIN,OVP}$  or  $V_{ZCS}$  exceeds  $V_{ZCS,OVP}$ , the over voltage protection is triggered and the IC will discharge  $V_{VIN}$  by an internal current source  $I_{VIN,OVP}$ . Once  $V_{VIN}$  is below  $V_{VIN,OFF}$  the IC will shut down and be charged again by BUS voltage through start up resistor. If the over voltage condition still exists, the system will operate in hiccup mode.

Thus, the turns of the auxiliary winding  $N_{\text{AUX}}$  and the resistor divider is related with the OVP function.

$$\frac{V_{ZCS_OVP}}{V_{OVP}} = \frac{N_{AUX}}{N} \times \frac{R_{ZCSD}}{R_{ZCSU} + R_{ZCSD}} (8)$$
$$\frac{V_{VIN_OVP}}{V_{OVP}} \ge \frac{N_{AUX}}{N} (9)$$

Where  $V_{OVP}$  is the output over voltage specification;N and  $N_{AUX}$  are the turns of main winding and auxiliary winding separately.  $R_{ZCSU}$  and  $R_{ZCSD}$  compose the resistor divider.

The turns ratio of N to  $N_{AUX}$  and the ratio of  $R_{ZCSU}$  to  $R_{ZCSD}$  could be induced from equation (8) and (9).

#### Short Circuit Protection (SCP)

When the output is shorted to ground, the output voltage is clamped to zero. The voltage of the auxiliary winding is proportional to the output winding, so  $V_{VIN}$  will drop down without auxiliary winding supply. Once  $V_{VIN}$  is below  $V_{VIN,OFF}$ , the IC will shut down and be charged again by the BUS voltage through the start up resistor. If the short circuit condition still exists, the system will operate in hiccup mode.

In order to guarantee SCP function not effected by voltage spike of auxiliary winding, a filter resistor  $R_{AUX}$  is needed (10 $\Omega$  typically) shown in Fig.9.

#### Line regulation modification

The IC provides line regulation modification function to improve line regulation performance.

Due to the sample delay of Source pin and other internal delay, the output current increases with increasing input BUS line voltage. A small compensation voltage  $\Delta V_{SE-C}$  is added to Source pin during ON time to improve such performance. This  $\Delta V_{SE,C}$  is adjusted by the upper resistor of the divider connected to ZCS pin.

$$\Delta V_{\text{SE,C}} = V_{\text{BUS}} \times \frac{N_{\text{AUX}}}{N} \times \frac{1}{R_{\text{ZCSU}}} \times k_1 (10)$$

Where  $R_{ZCSU}$  is the upper resistor of the divider;  $k_1$  is an internal constant as the modification coefficient.

The compensation is mainly related with  $R_{ZCSU}$ , larger compensation is achieved with smaller  $R_{ZCSU}$ . Normally,  $R_{ZCS}$  ranges from 100k $\Omega$ ~1M $\Omega$ .

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Then  $R_{ZCSD}$  can be selected by,

$$\frac{\frac{V_{ZCS_{OVP}}}{V_{OUT}} \times \frac{N}{N_{AUX}}}{1 - \frac{V_{ZCS_{OVP}}}{V_{OUT}} \times \frac{N}{N_{AUX}}} \times R_{ZCSU} > R_{ZCSD} (11),$$

And,

$$R_{zCSD} \ge \frac{\frac{V_{ZCS_OVP}}{V_{OVP}} \times \frac{N}{N_{AUX}}}{1 - \frac{V_{ZCS_OVP}}{V_{OVP}} \times \frac{N}{N_{AUX}}} \times R_{zCSU} (12)$$

Where  $V_{OVP}$  is the output over voltage protection specification;  $V_{OUT}$  is the rated output voltage;  $R_{ZCSU}$  is the upper resistor of the divider; N and  $N_{AUX}$  are the turns of main winding and auxiliary winding separately.

#### **Power design Reference**

Products	Input range	output current	application	temperature rise
SY58594A	176Vac~264Vac	0.3A	20W/T8	37°C
SY58594A	176Vac~264Vac	0.3A	17W/T8	31°C
SY58594A	176Vac~264Vac	0.3A	15W/T8	30°C
SY58594A	176Vac~264Vac	0.3A	13W/T8	26°C
SY58594A	176Vac~264Vac	0.3A	10W/T8	23°C
SY58594A	176Vac~264Vac	0.2A	18W/T8	21°C
SY58594A	90Vac~132Vac	0. <b>3</b> A	12W/T8	48°C
SY58594A	90Vac~132Vac	0.3A	10W/T8	37°C
SY58594A	90Vac~132Va	0.2A	14W/T8	37°C
SY58594A	90Vac~132Vac	0.2A	12W/T8	31°C
SY58594A	90Vac-132Vac	0.2A	10W/T8	23°C

SY58594A

The test is operated in natural cooling condition at  $25^{\circ}$ C ambient temperature.



### **Power Device Design**

#### **MOSFET and Diode**

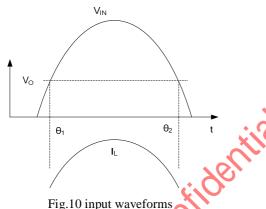
When the operation condition is with maximum input voltage and full load, the voltage stress of MOSFET and output power diode is maximized;

$$V_{\text{MOS}_{\text{DS}_{\text{MAX}}}} = \sqrt{2} V_{\text{AC}_{\text{MAX}}} (13)$$

$$V_{D R MAX} = \sqrt{2} V_{AC MAX} (14)$$

Where  $V_{AC,MAX}$  is maximum input AC RMS voltage. When the operation condition is with minimum input voltage and full load, the current stress of MOSFET and power diode is maximized.

#### Inductor (L)

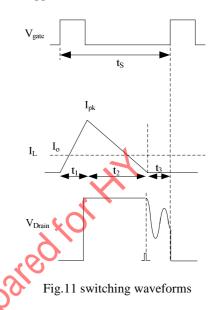


The power is transferred from AC input to output only when the input voltage is larger than output voltage in Buck converter. The input voltage and inductor current waveforms are shown in Fig.10, where  $\theta_1$  and  $\theta_2$  are the time that input voltage is equal to output voltage.

In Quasi-Resonant mode, each switching period cycle  $t_s$  consists of three parts: current rising time  $t_1$ , current falling time  $t_2$  and quasi-resonant time  $t_3$  shown in Fig.11.

The system operates in the constant on time mode to achieve high power factor. The ON time increases with the input AC RMS voltage decreasing and the load increasing. When the operation condition is with minimum input AC RMS voltage and full load, the ON time is maximized. On the other hand, when the input voltage is at the peak value, the OFF time is maximized. Thus, the minimum switching frequency  $f_{S-MIN}$  happens at the peak value of input voltage with minimum input AC

RMS voltage and maximum load condition; Meanwhile, the maximum peak current through MOSFET and the transformer happens.



Once the minimum frequency  $f_{S-MIN}$  is set, the inductance of the transformer could be calculated. The design flow is shown as below:

(a) Preset minimum frequency  $f_{S-MIN}$ 

(b) Compute relative t<sub>s</sub>, t<sub>1</sub>

$$t_{s} = \frac{1}{f_{s\_MIN}} (15)$$
  
$$t_{1} = \frac{t_{s} \times (V_{OUT} + V_{DF})}{(\sqrt{2}V_{AC\_MIN} + V_{DF})} (16)$$

 $t_2 = t_s - t_1 (17)$ 

Where  $V_{DF}$  is the forward voltage of the diode (c) Design inductance L

$$\theta_{1} = \arcsin\left(\frac{V_{OUT}}{\sqrt{2}V_{AC\_MIN}}\right) \times \frac{1}{\pi} \times \frac{1}{2 \times f_{AC}} \quad (18)$$

$$\theta_{2} = \frac{1}{2 \times f_{AC}} - \theta_{1} \quad (19)$$

$$L = \frac{\eta \times f_{AC} \times V_{OUT} \times t_{1}}{P_{OUT}} \times \frac{\cos(2\pi f_{AC} \times \theta_{1}) - \cos(2\pi f_{AC} \times \theta_{2})}{2\pi f_{AC}} - V_{OUT}(\theta_{2} - \theta_{1})]$$
(20)

Where  $\eta$  is the efficiency; P<sub>OUT</sub> is rated full load power;

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(d) compute inductor maximum peak current  $I_{L-PK-MAX}$ .

$$\mathbf{I}_{L_{PK}_{MAX}} = \frac{(\sqrt{2}\mathbf{V}_{AC_{MIN}} - \mathbf{V}_{OUT}) \times \mathbf{t}_{1}}{L} (21)$$

Where I<sub>L-PK-MAX</sub> is maximum inductor peak current ;

(f) compute RMS current of the inductor

I<sub>L RMS MAX</sub> is Inductor RMS current of whole AC period

$$I_{L_{RMS}MAX} = \frac{t_{1}}{\sqrt{3} \times L} \sqrt{V_{AC_{MIN}}^{2} + V_{OUT}^{2} - \frac{4\sqrt{2}V_{AC_{MIN}} \times V_{OUT}}{\pi}}$$

(22)

(g) compute RMS current of the MOSFET

$$I_{L\_RMS\_MAX} = \sqrt{\frac{t_1}{3t_s}} \times \frac{t_1}{L} \sqrt{V_{AC\_MIN}^2 + V_{OUT}^2} - \frac{4\sqrt{2}V_{AC\_MIN} \times V_{OUT}}{\pi}$$

(23)

#### inductor design (N, NAUX)

the parameters below are necessary:

 Necessary parameters

 Inductance
 L

 inductor maximum current
  $I_{L_PK_MAX}$  

 inductor maximum RMS current
  $I_{L_RMS_MAX}$  

 The design rules are as followed:
 O 

(a) Select the magnetic core style, identify the effective area  $A_{e_{-}}$ 

(b) Preset the maximum magnetic flux  $\Delta B$ 

ΔB=0.22~0.26T

(c) Compute primary turn N N= $U_{MT} \times I_{L,PK,MAX}$  (24)

(d) compute auxiliary turn  $N_{AUX}$ 

 $N_{AUX} = N \times \frac{V_{VIN}}{V_{OUT}}$  (25)

Where  $V_{VIN}$  is the working voltage of VIN pin (10V~11V is recommended).

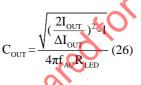
(e) Select an appropriate wire diameter

With  $I_{L-RMS-MAX}$ , select appropriate wire to make sure the current density ranges from  $4A/mm^2$  to  $10A/mm^2$ .

(f) If the winding area of the core and bobbin is not enough, reselect the core style, go to (a) and redesign the transformer until the ideal transformer is achieved.

#### Output capacitor Cour

Preset the output current ripple  $\Delta I_{OUT}$ ,  $C_{OUT}$  is induced by



Where  $I_{OUT}$  is the rated output current;  $\Delta I_{OUT}$  is the demanded current ripple;  $f_{AC}$  is the input AC supply frequency;  $R_{LED}$  is the equivalent series resistor of the LED load.

#### Layout

(a) To achieve better EMI performance and reduce line frequency ripples, the output of the bridge rectifier should be connected to the BUS line capacitor first, then to the switching circuit.

(b) The circuit loop of all switching circuit should be kept small.

(c) The connection of ground is recommended as:

Ground ①: ground of BUS line capacitor Ground ②: ground of bias supply capacitor and GND pin Ground ③: ground node of auxiliary winding Ground ④: ground of signal trace except GND pin Ground ⑤: ground node of current sample resistor.

(d) bias supply trace should be connected to the bias supply capacitor first instead of GND pin. The bias supply capacitor should be put beside the IC.

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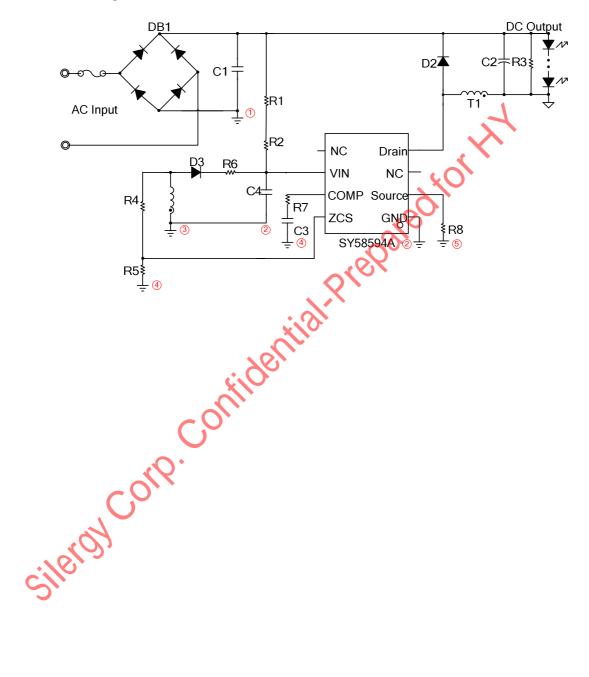


(e) Loop of 'Source pin – current sample resistor – GND

pin' should be kept as small as possible.

(g) The control circuit is recommended to be put outside the power circuit loop.

(f) The resistor divider connected to ZCS pin is recommended to be put beside the IC.





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### **Design Example**

A design example of typical application is shown below step by step.

#1. Identify design specification

Design Specification			
V <sub>AC</sub> (RMS)	176V~264V	V <sub>OUT</sub>	24V
I <sub>OUT</sub>	300mA	η	92%

#2.Inductor design (L)

Refer to Power Device Design

	C		
Conditions			
V <sub>AC,MIN</sub>	176V	V <sub>AC-MAX</sub>	264V
P <sub>OUT</sub>	7.2W	f <sub>S-MIN</sub>	55kHz
$(\mathbf{a})f_{S,MIN}$ is preset			2401
$f_{S_{MIN}}$ =46kHz			ale a
· · · •		N time $t_1$ at the peak of input	t voltage.
$t_{\rm s} = \frac{1}{f_{\rm s\_MIN}} = 21.74\mu$	<i>l</i> s	tial. P	
$t_1 = \frac{t_s \times (V_{OUT} + V_{AC_{MIN}} + V_{AC_{MIN}} + V_{AC_{MIN}})}{(\sqrt{2}V_{AC_{MIN}} + V_{AC_{MIN}} + V_{AC_{MIN}})}$	$(D_{DF}) = \frac{21.74 \text{us} \times (24 \text{V} + 1)}{(\sqrt{2} \times 176 \text{V} + 1)}$	$\frac{1V}{V} = 2.17 \mu s$	
$t_2 = t_s - t_1 = 21.74 \mu s$	s-2.17μs = 19.57μs		
(c) Compute the in	iductance L 🛛 👝 🚫		
$\theta_1 = \arcsin(\frac{V_{OU}}{\sqrt{2}V_{AC}})$	$\frac{T}{2}$ )× $\frac{1}{\pi}$ × $\frac{1}{2\times f_{AC}}$ = arc	$\sin(\frac{24V}{\sqrt{2}\times176V}) \times \frac{1}{\pi} \times \frac{1}{2\times504}$	$\frac{1}{Hz} = 3.074 \times 10^{-4} s$
$\theta_2 = \frac{1}{2 \times f_{AC}} - \theta_1 =$	$=\frac{1}{2\times50HZ}$ -3.074×10 <sup>-4</sup>	$s = 9.693 \times 10^{-3} s$	
$\mathbf{L} = \frac{\eta \times f_{AC} \times \mathbf{V}_{OUT}}{\mathbf{P}_{OUT}}$	×t <sub>T</sub> ×	$\frac{\pi \times f_{AC} \times \theta_2}{2} - \mathbf{V}_{OUT}(\theta_2 - \theta_1)$	
$\left[\sqrt{2}V_{AC_{MIN}}\right] \propto \frac{\cos(2)}{2}$	$\frac{2 \times \pi \times f_{AC} \times \theta_1) - \cos(2 \times \pi \times f_{AC})}{2 \times \pi \times f_{AC}}$	$\frac{(\pi \times f_{AC} \times \theta_2)}{(\theta_2 - \theta_1)} - V_{OUT}(\theta_2 - \theta_1)$	)]
$=\frac{0.92\times50Hz\times24}{7.2W}$	$\frac{W \times 2.17 \mu s}{V} \times$		
	$2\pi \times 50Hz \times 3.074 \times 10^{-4}$	$s_{z}(s) - \cos(2\pi \times 50Hz \times 9.693 \times 10^{-3})$	$\frac{10^{-3}s}{s} - 24V(9.693 \times 10^{-3}s - 3.074 \times 10^{-4})$
$=451 \mu H$			
( <b>d</b> ) compute induc	tor maximum peak curr	ent ILPK-MAX.	

(d) compute inductor maximum peak current  $I_{\text{L-PK-MAX}}.$ 



$$I_{L_{PK}_{MAX}} = \frac{(\sqrt{2}V_{AC_{MIN}} - V_{OUT}) \times t_1}{L} = \frac{(\sqrt{2} \times 176 - 24) \times 2.17 \mu s}{451 \mu H} = 1.082A$$

Where  $I_{\text{L-PK-MAX}} \text{ is maximum inductor peak current };$ (f) compute RMS of the inductor current  $I_{L-RMS-MAX}$ 

$$I_{L\_RMS\_MAX} = \frac{t_1}{\sqrt{3} \times L} \sqrt{V_{AC\_MIN}^2 + V_{OUT}^2 - \frac{4\sqrt{2}V_{AC\_MIN} \times V_{OUT}}{\pi}}$$
$$= \frac{2.17\mu s}{\sqrt{3} \times 451\mu H} \sqrt{176V^2 + 24V^2 - \frac{4\sqrt{2} \times 176V \times 24V}{\pi}}$$
$$= 0.43A$$

$\sqrt{3} \times 451 \mu H$ = 0.43A	Y 2	π	L	
#3. Select power	r MOSFET and power dio	de		
Refer to Power	Device Design		, 40 <sup>1</sup>	
Known conditio	ns at this step		0	
V <sub>AC-MAX</sub>	264V	η	92%	
V <sub>OUT</sub>	24V			
			<u> </u>	

Compute the voltage and the current stress of MOSFET:

Compute the voltage and the current stress of MOSFET:  

$$I_{L_{RMS_MAX}} = \sqrt{\frac{t_1}{3t_s}} \times \frac{t_1}{L} \sqrt{V_{AC_{-MIN}}^2 + V_{OUT}^2} - \frac{4\sqrt{2}V_{AC_{-MIN}} \times V_{OUT}}{\pi}$$

$$= \sqrt{\frac{2.17 \mu s}{3 \times 21.74 \mu s}} \times \frac{2.17 \mu s}{451 \mu H} \times \sqrt{176V^2 + 24V^2} - \frac{4\sqrt{2} \times 176V \times 24V}{\pi}$$

$$= 0.136A$$
#4. Select the output capacitor Corr  
Refer to Power Device Design  
Conditions  
Iour 300mA AIour 0.3Iour  
IAC 50Hz R<sub>LED</sub> 7 × 1.6Ω



$$C_{OUT} = \frac{\sqrt{(\frac{2I_{OUT}}{\Delta I_{OUT}})^{2} - 1}}{4\pi f_{AC} R_{LED}}}{\frac{\sqrt{(\frac{2 \times 0.3A}{0.5 \times 0.3A})^{2} - 1}}{4\pi \times 50 Hz \times 7 \times 1.6\Omega}}{= 550 \mu F}$$

#6. Set VIN pin

Refer to Start up

Refer to Start up			1
Conditions			
V <sub>BUS-MIN</sub>	176V×1.414	V <sub>BUS-MAX</sub>	264V×1.414
I <sub>ST</sub>	15μA (typical)	V <sub>IN-ON</sub>	16V (typical)
I <sub>VIN-OVP</sub>	2mA (typical)	t <sub>st</sub>	500ms (designed by user)
(a) $R_{ST}$ is preset $R_{ST} < \frac{V_{BUS}}{I_{ST}} = \frac{176}{1}$	<u>V×1.414</u> =16.59MΩ,	Jential-Pres	pared
$R_{ST} > \frac{V_{BUS}}{I_{VIN_OVP}} = \frac{2}{2}$	$\frac{264\text{V}\times1.414}{2\text{mA}} = 186.7\text{k}\Omega$	tialPh	
Set R <sub>ST</sub>		0	
$R_{st} = 470 k\Omega \times 2 =$	-950kΩ	50	
( <b>b</b> ) Design C <sub>VIN</sub>	co		
$C_{VIN} = \frac{(\frac{V_{BUS}}{R_{ST}} - I_{ST})}{V_{VIN_{C}}}$			

$$R_{ST} < \frac{V_{BUS}}{I_{ST}} = \frac{176V \times 1.414}{15\mu A} = 16.59 M\Omega ,$$
$$R_{ST} > \frac{V_{BUS}}{I_{VIN_{OVP}}} = \frac{264V \times 1.414}{2mA} = 186.7 k\Omega$$

$$R_{st}$$
=470k $\Omega$ ×2=950k $\Omega$ 

$$C_{VIN} = \frac{(\frac{V_{BUS}}{R_{ST}} - I_{ST}) \times t_{ST}}{V_{VIN_{ON}}}$$
  
= 
$$\frac{(\frac{176V \times 1.414}{950K\Omega} - 15\mu A) \times 500ms}{16V}$$
  
= 7.72µF

Set C<sub>VIN</sub>

 $C_{VIN}$ =10 $\mu F$ 

#7 Set COMP pin

Refer to Internal pre-charge design for quick start up



# <u>SY58594A</u>

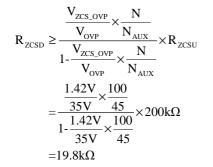
Parameters designed			
R <sub>COMP</sub>	500Ω	V <sub>COMP,IC</sub>	600mV
C <sub>COMP1</sub>	2μF	C <sub>COMP2</sub>	0

#8 Set current sense resistor to achieve ideal output current

#### Refer to constant-current control

Known conditions at thi	s step		
V <sub>REF</sub>	0.3V	I <sub>OUT</sub>	0.3A
The current sense resiste	or is		
$R_{\rm S} = \frac{V_{\rm REF}}{2 \times I_{\rm OUT}} = \frac{0.3}{2 \times 0.3 A}$	$T = 0.5\Omega$		, for HT
#9 set ZCS pin			$\lambda^{\mathbf{v}}$
-			
Refer to Line regulation	<b>n modification</b> and <b>Ove</b>	r Voltage Protection (	OVP) & Open Loop Protection (OLP
First identify R <sub>ZCSU</sub> need	-	ales a	<u> </u>
Known conditions at thi	s step	<u> </u>	
Parameters Designed			
R <sub>ZCSU</sub>	200kΩ	<u> </u>	68
Then compute R <sub>ZCSD</sub>		ellr.	
V <sub>ZCS_OVP</sub>	1.42V	V <sub>OVP</sub>	35V
V <sub>OUT</sub>	24V	000	
Parameters designed	~ O`		<b>I</b>
R <sub>ZCSU</sub>	200kΩ		
N	100	N <sub>AUX</sub>	45
$R_{ZCSD} < \frac{\frac{V_{ZCS_OVP}}{V_{OUT}} \times \frac{N}{N_{AI}}}{\frac{V_{ZCS_OVP}}{V_{OUT}} \times \frac{N}{N_{AI}}}$ $= 30.2k\Omega$	<u> </u>		

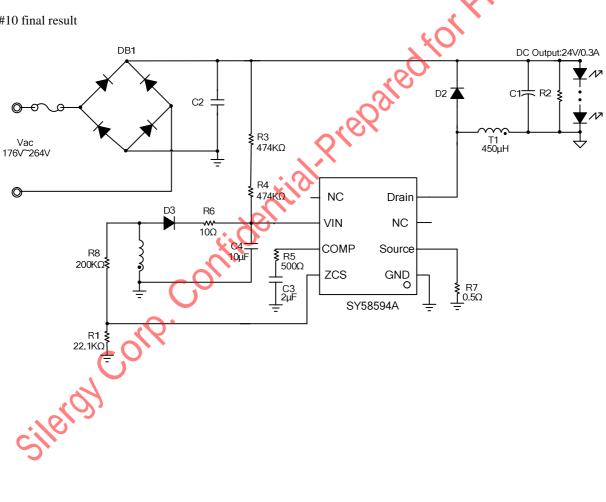




 $R_{ZCSD} \mbox{ is set to }$ 

$$R_{zcsd} = 22.1 k\Omega$$

#10 final result





SO8 Package Outline & PCB Layout Design

